

EUV resist outgassing activity at Selete



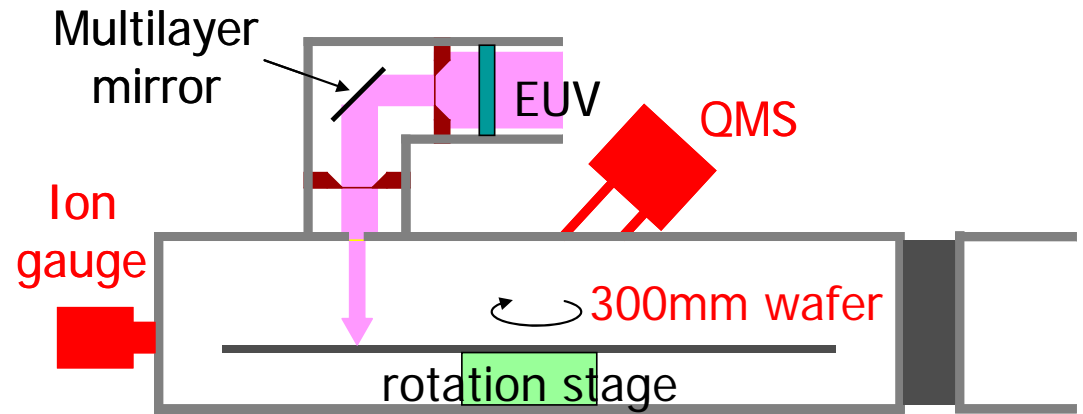
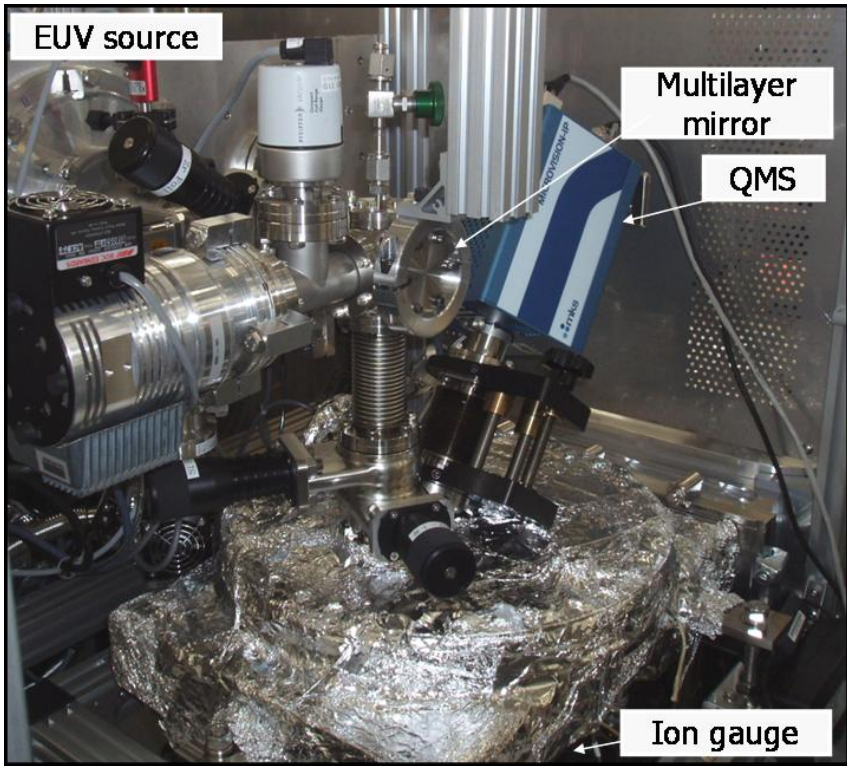
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- Evaluation tools and methods
- Present activities and results
- Summary
- Future Plans
- Acknowledgement

Pressure rise method

QMS analysis



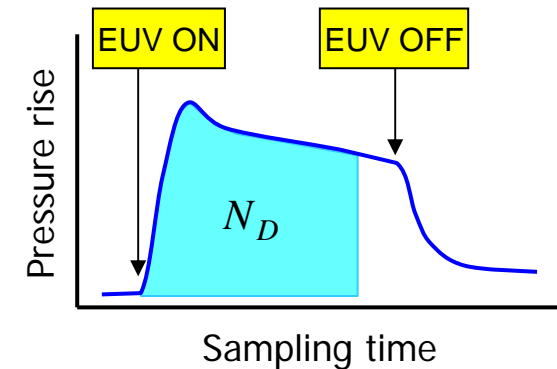
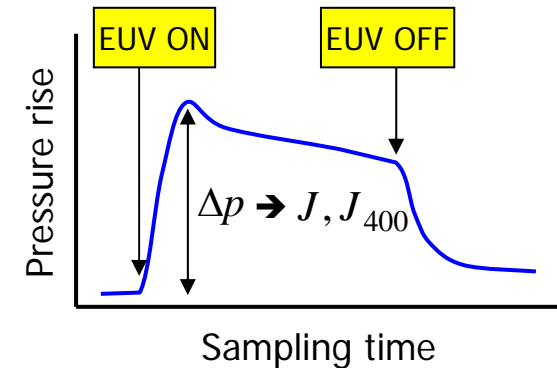
EUV Source	: EQ-10MR
Power on Wafer	: 0.03mW/cm ²
Exposure area	: 1.43 cm ²
Base pressure	: 8x10⁻⁷ Pa

Resist outgassing '**RATE**' [unit : molecules·cm⁻²·s⁻¹]

Maximum rate during exposure → indicator for exposure tool management

$$J = \frac{\Delta p S_e}{RTA} N_A \quad (\text{evaluated EUV intensity})$$

$$J_{400} = \frac{\Delta p S_e}{RTA} N_A \frac{400}{I} \quad (400\text{mW}\cdot\text{cm}^{-2} \text{ assumed})$$



Resist outgassing '**AMOUNT**' [unit : molecules·cm⁻²]

AMOUNT dependence on exposure dose → indicator for resist improvement

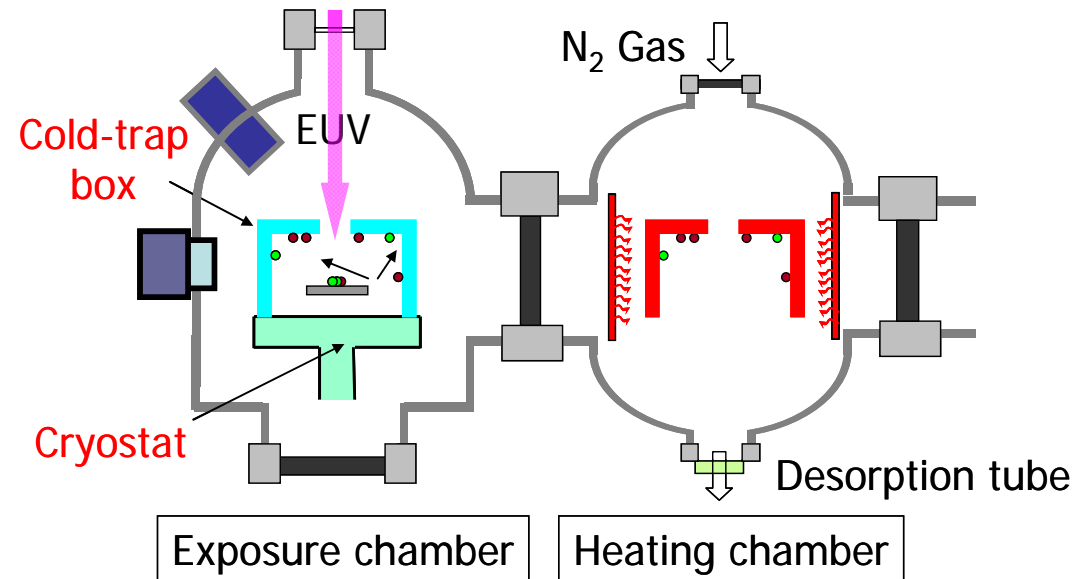
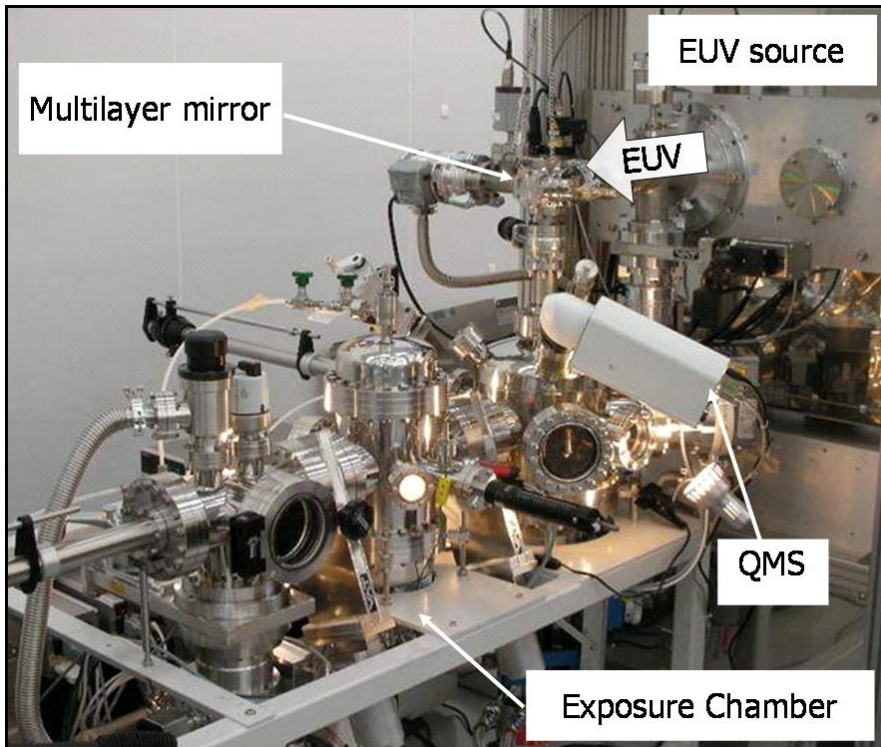
$$N_D = \sum_{i=0}^t \frac{\Delta P_i S_e}{RTA} (t_{i+1} - t_i) N_A$$

Δp : pressure rise
 S_e : effective pumping speed
 R : Gas constant
 T : temperature
 A : area of exposure

N_A : avogadro's number
 I : EUV intensity
 (subscript)
 i : time
 D : established dose

Rate and amount calculations based on the pressure variations.

GC-MS method



EUV Source	: EQ-10MR
Power on Wafer	: 0.014mW/cm ²
Exposure area	: 1.69 cm ²
Base pressure	: 1x10⁻⁷ Pa

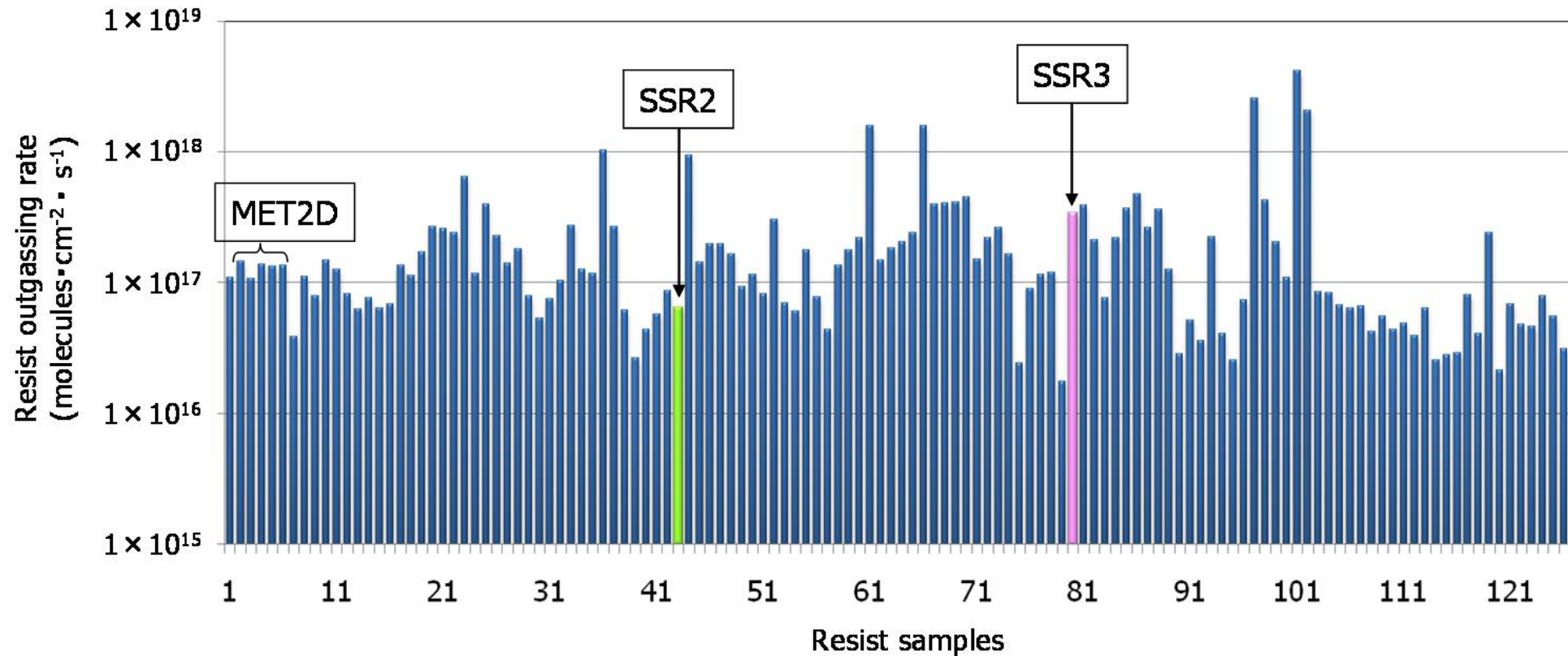
Methods	Description	Evaluation time	Selete
Pressure rise	<ul style="list-style-type: none"> <input type="checkbox"/> Simple and quick for quantitative analysis. <input checked="" type="checkbox"/> Component identification not possible. 	2 hours/sample	○
GC-MS	<ul style="list-style-type: none"> <input type="checkbox"/> Component identification possible. <input checked="" type="checkbox"/> CO₂ cannot be detected. <input checked="" type="checkbox"/> Low throughput. 	1 day/sample	○
QMS	<ul style="list-style-type: none"> <input type="checkbox"/> In-situ qualitative analysis possible <input checked="" type="checkbox"/> Quantitative analysis not possible. <input checked="" type="checkbox"/> Qualitative analysis inaccuracy due to fragmentation effect. 	2 hours/sample	○
Witness mirror	<ul style="list-style-type: none"> <input type="checkbox"/> Contamination level directly observed. <input checked="" type="checkbox"/> Low throughput and high cost. 	A few days/sample	△

Pressure rise, GC-MS and QMS methods are applied for resist outgassing evaluations.

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Pressure rise method

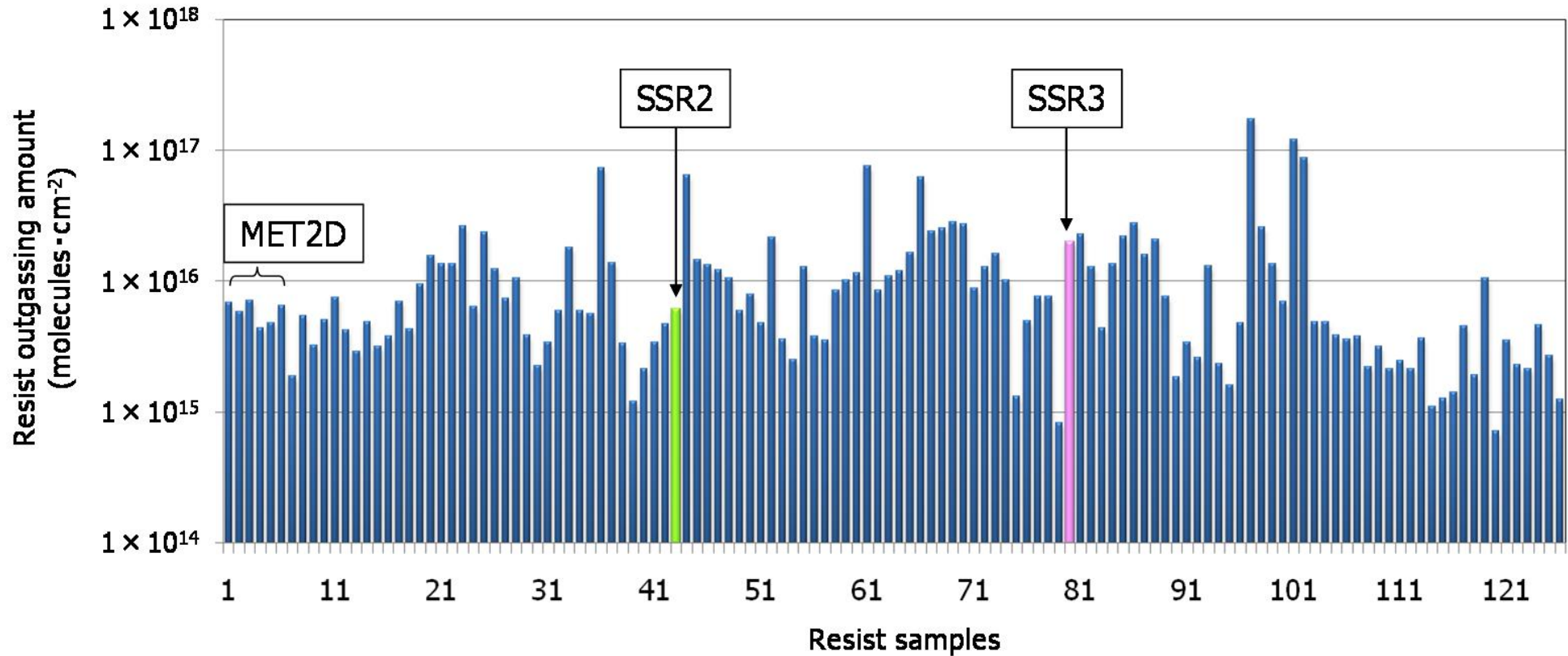
for Quantification by **RATE**



More than **120 samples** analyzed for resist outgassing rate.

Pressure rise method

for Quantification by **AMOUNT**



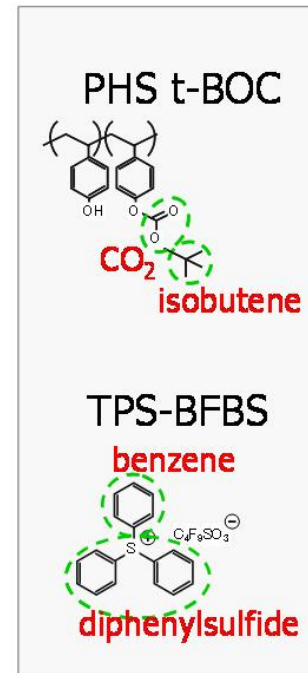
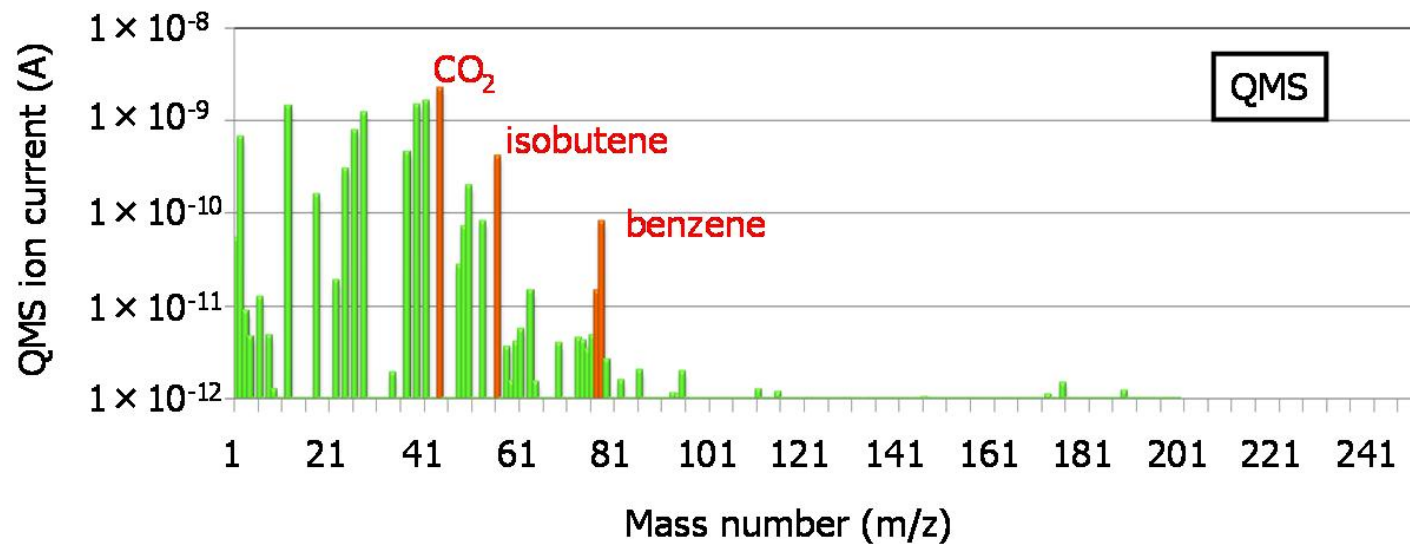
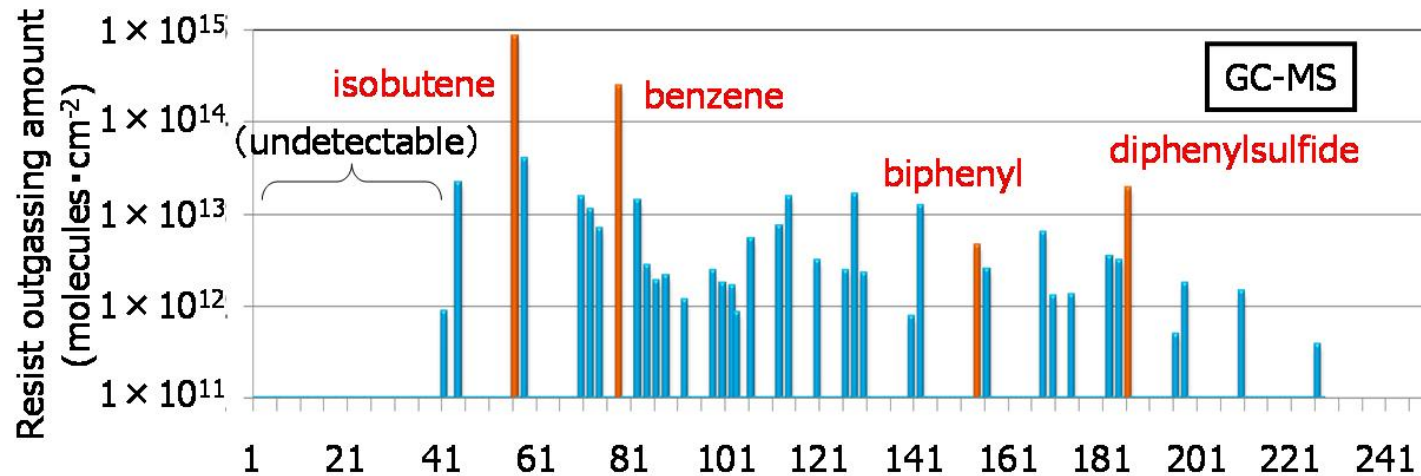
More than **120 samples** analyzed for resist outgassing amount.

GC-MS method

&

QMS analysis

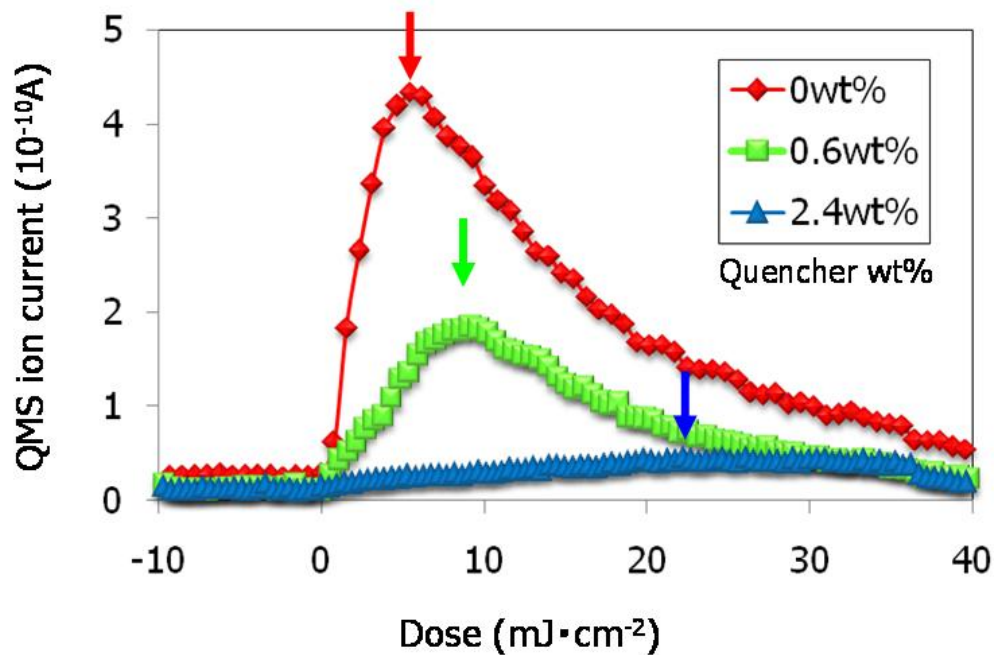
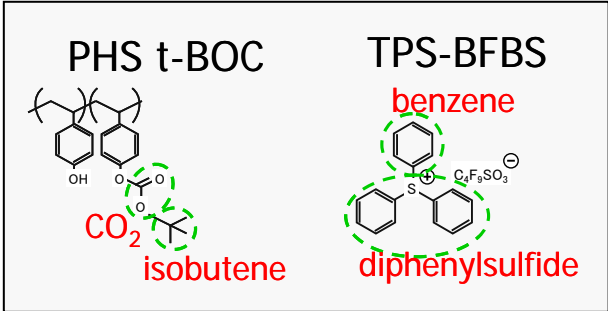
for Qualitative analysis



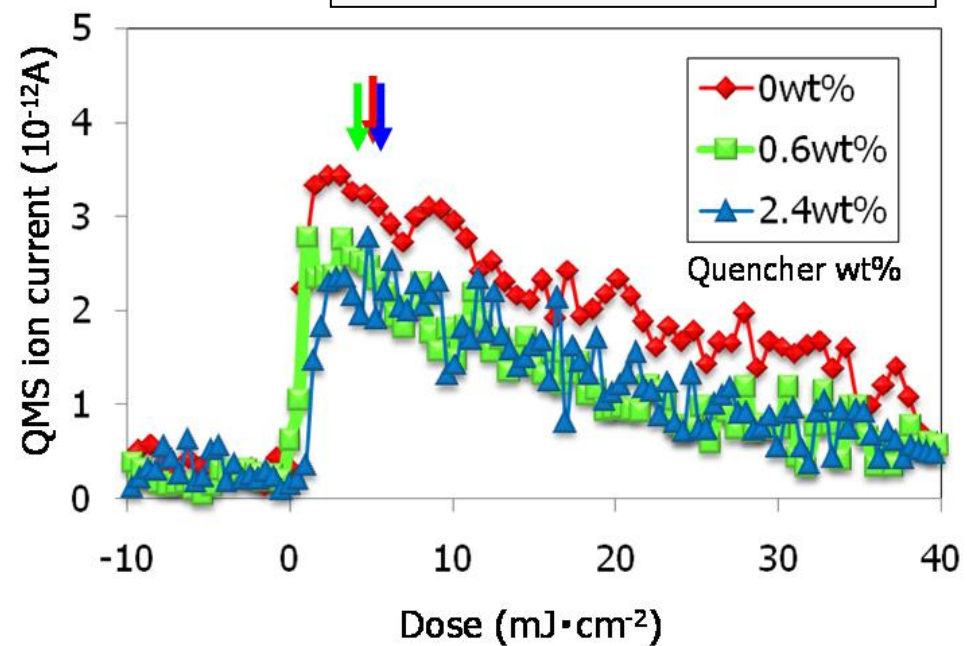
- GC-MS effective for component analysis. CO₂ cannot be detected.
- Fragmentation in QMS cause large difference in detected spectra.

QMS analysis

for Reaction mechanisms



CO₂ (m/z=44) QMS spectra



C₆H₅ (m/z=77) QMS spectra

Dependence of component peak positions observed.
 CO₂ (m/z=44) dependent, C₆H₅ (m/z=77) not dependent.

<p>Quantification (Quick Screening)</p>	<p>Pressure rise method</p> <p>Screening of resist samples received prior to exposure.</p>
<p>Component analysis</p>	<p>GC-MS method</p> <p>Improvement of resist samples based on new resist components.</p>
<p>Mechanism analysis</p>	<p>QMS analysis</p> <p>GC-MS method</p> <p>Basic study to improve tools and control methods.</p>

- Quantification (Quick Screening)

Resist outgassing rate and amount evaluations were performed for more than **120 samples** using the **pressure rise** method, **prior to exposure**.

- Component analysis

GC-MS effective and accurate in the analysis of resist outgassing components. (CO₂ cannot be detected).

- Mechanism analysis

QMS is highly recommended for component reaction mechanism analysis during exposure.

GC-MS method is also applied to provide more accurate component identification for mechanism analysis.

Selete applies resist outgassing methods depending on the **analysis objectives**.

- Further improvement of analysis result **accuracy**.
- **Discussion** with exposure tool makers (Nikon and Canon) underway.
- Establish specific resist outgassing limits for **pre-production** level.
- **Collaboration** with other research consortiums, tool and material suppliers, universities and research groups.

Acknowledgement

- A part of this work is supported by New Energy and Industrial Technology Development Organization (**NEDO**).
- Selete member companies (EUV Lithomask program).